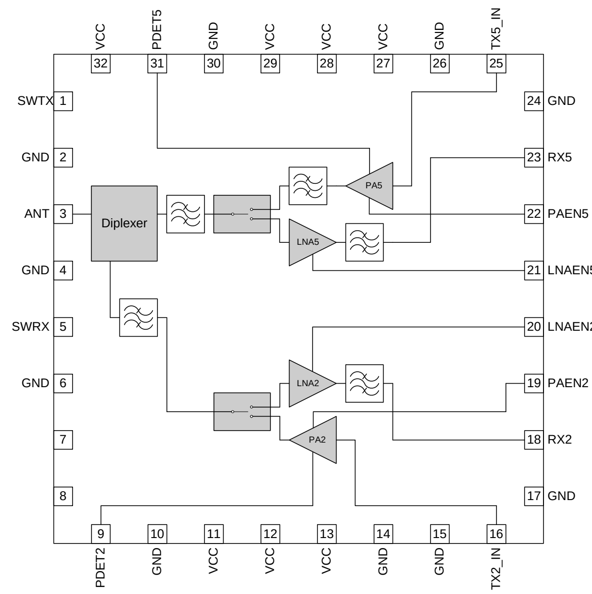
RF5608

3.0V TO 3.6V, DUAL-BAND FRONT-END MODULE

Package Style: 32-Pin, 5mmx5mmx0.9mm



Functional Block Diagram

Features

- Single-Module Radio Front-End
- Single Supply Voltage 3.0V to 3.6V
- Integrated 2.5GHz & 5GHZ PA's, Diplexer LNA for both High and Low Band, Filters & Switches for TX & RX
- P_{OUT}=18dBm, 11g, OFDM, <3% EVM and P_{OUT}=16dBm, 11a, OFDM, <4% EVM

Applications

- IEEE802.11a/b/g/n WiFi Applications
- Single-Chip RF Front-End Module
- 2.5GHz and 5GHz ISM Bands Applications
- WiFi Systems
- Portable Battery-Powered Equipment

Product Description

The RF5608 is a single-chip dual-band integrated front-end module (FEM) for high-performance WiFi applications in the 2.5GHz and 5GHz ISM bands. The RF5608 addresses the need for aggressive size reduction for a typical 802.11a/b/g RF front-end design and greatly reduces the number of components outside of the core chipset therefore minimizing the footprint and assembly cost of the overall 802.11a/b/g solution. The FEM contains integrated power amplifiers for 2.5GHz and 5GHz, TX/RX switch for each band, low noise amplifier for the 5.0GHz receive band, matching components, bypass capacitors, built-in power detector for both bands, and band pass filters for both transmit paths and some filtering for both receive paths. The device is manufactured on lead frame with InGap HBT and pHEMT processes. The RF5608 module is a 5mmx5mmx0.9mm package with 32-pins and a backside ground. The RF5608 greatly minimizes next level board space and allows for simplified integration.

Ordering Information

RF5608SQ	Standard 25 piece bag
RF5608SR	Standard 100 piece reel
RF5608TR13	Standard 2500 piece reel
RF5608PCK-410	Fully Assembled Evaluation Board with 5 Loose Sample Pieces

Optimum Technology Matching® Applied

☐ GaAs HBT	☐ SiGe BiCMOS	☑ GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET	☐ Si BiCMOS	☑ Si CMOS	☐ RF MEMS
☑ InGaP HBT	☐ SiGe HBT	☐ Si BJT	☐ LDMOS

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.3 to +5.4	V_{DC}
Power Control Voltage (V_{REG})	-0.5 to +3.5	V
DC Supply Current	400	mA
Input RF Power	0	dBm
Operating Ambient Temperature	0 to +70	°C
Reduced Performance Temps	-30 to 0	°C
	+70 to +85	°C
Storage Temperature	-40 to +150	°C
Moisture Sensitivity	JEDEC Level TBD	

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Transmit	2.4		2.5	GHz	Nominal Conditions: T=+25°C, V_{CC}(b/g)=3.3V, PAEN_g=2.85V, Freq=2.4GHz to 2.5GHz, unless otherwise noted.
Compliance					IEEE802.11b, IEEE802.11g FCC CFR 15.247, 0.205, 0.209
Output Power 11g	16.5	18		dBm	With a standard IEEE802.11g waveform, OFDM, 54Mbps, 64 QAM, over temperature range -30°C to +85°C, and V_{CC}=3.0V to 3.6V
EVM					RMS, mean with a standard IEEE802.11g waveform, OFDM, 54Mbps, 64 QAM at 11g rated output power over temperature range -30°C to +85°C and V_{CC}=3.0V to 3.6V
P_{OUT}=18dBm		3	4.5	%	
P_{OUT}=14dBm		2	2.5	%	
Output Power 11b	20	21		dBm	With a standard IEEE802.11b waveform, over temperature range -30°C to +85°C, and over V_{CC}=3.0V to 3.6V
Adjacent Channel Power					At 11b rated output power with 1Mbps and 11Mbps 11b waveform over temperature range -30°C to +85°C, and over V_{CC}=3.0V to 3.6V
ACP1		-38	-30	dBc	
ACP2		-56	-50	dBc	
Gain	25	27		dB	
Gain Variance	-2.5		+2.5	dB	Over Temperature range -10°C to +70°C and over Frequency
Power Detect					
Voltage Range	0.8	0.95	1.2	V	At 20dBm
	0.2	0.25	0.35	V	At 10dBm P_{OUT}
Output Resistance		10		kΩ	
Output Capacitance		10		pF	
Power Detector Accuracy	-1.5		+1.5	dB	Into 3:1 VSWR
Sensitivity					
>14dBm		75		mV/dB	
0<P_{OUT}<14dBm		25		mV/dB	

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Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Transmit, cont.					
Current Operating		125	160	mA	RF P_{OUT}=14dBm, 54Mbps, IEEE802.11g
		160	230	mA	RF P_{OUT}=18dBm, 11Mbps, IEEE802.11b
		200	275	mA	RF P_{OUT}=20dBm, 11g or 11b
Quiescent		90	125	mA	V_{CC}=ON, PAEN=ON, RF=OFF
PAEN		75	100	uA	Over full temp range and V_{REG}
Shutdown		5	10	uA	Voltage range PAEN≤0.2V
Second Harmonic					P_{OUT}=20dBm, 1Mbps, 11b mode
Second		-49	-45	dBm	4.90GHz to 5.00GHz
Third		-46	-43	dBm	7.20GHz to 7.50GHz
Power Supply	3.0	3.3	3.6	V	
PAEN Voltage					
ON	2.0	3.0	3.2	V	TTL, 200mV less than V_{CC}
OFF		0	0.2	V	
Input Return Loss		-12	-9	dB	
Ruggedness Output VSWR	10:1			ratio	No damage, conditions: max operating voltage, max input power
Stability Output VSWR	4:1			ratio	
Turn-On/Off Time		0.5	1.0	µS	Output stable to within 90% of final gain, Note 1
5.0GHz Transmit					
Compliance					IEEE802.11a IEEE802.11j FCC CFR 15.247, 0.205, 0.209
Frequency					Nominal Conditions: T=+25°C, V_{CC}=3.3V, PAEN=3.0V, Freq range from 4.9GHz to 5.85GHz unless otherwise noted.
Band 1	4.9		5.1	GHz	
Band 2	5.10		5.35	GHz	
Band 3	5.35		5.65	GHz	
Band 4	5.65		5.825	GHz	
Band 1 P_{OUT}	11.5	13		dBm	RMS, mean with a standard IEEE802.11g waveform, OFDM, 54Mbps, 64 QAM V_{CC}=3.3V_{DC}, 0°C to +70°C over beta
EVM	2	3		%	
Band 2 P_{OUT}	11.5	13		dBm	
EVM	2	2.5		%	
Band 3 P_{OUT}	11.5	13		dBm	
EVM	2	2.5		%	
Band 3 P_{OUT}	14.5	16		dBm	
EVM	3	4		%	
Band 4 P_{OUT}	11.5	13		dBm	
EVM	2	2.5		%	
Band 4 P_{OUT}	14.5	16		dBm	
EVM	3	4		%	
Band 4 P_{OUT}	16.5	18		dBm	
EVM	4	7		%	

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
5.0GHz Transmit, cont.					
Gain	26	28		dB	
Gain Variance	-2		+2	dB	
Power Detect					
Voltage Range	0.8	0.9	1.0	V	At 18dBm P_{OUT}
	0.4	0.5	0.6	V	At 10dBm P_{OUT}
Output Resistance		TBD		kΩ	
Output Capacitance		TBD		pF	
Power Detector Accuracy	-1		+1	dB	At 3.0:1 VSWR at all Phases, power and all conditions
Sensitivity					
>10dBm		20		mV/dB	1V to 0.5V
$0<P_{OUT}<10$dBm		10		mV/dB	0V to 0.5V
Current Operating		180		mA	RF P_{OUT}=18dBm, 54Mbps, 11a
		100		mA	RF P_{OUT}=13dBm, 54Mbps, 11a
Quiescent			10	mA	V_{CC}=ON, PAEN=ON, RF=OFF
PAEN		TBD		µA	PAEN<0.2V
Shutdown		85		µA	
V_{CC}, Supply Voltage	3.0	3.3	3.6	V	
PAEN Voltage					
ON	2.8	3.0	3.2	V	TTL, 200mV less than V_{CC}
OFF		0	0.2	V	
Input Impedance		50	2:1	Ω	
Max Input Power Operational			-5	dBm	
Rated Input Power Withstand			0	dBm	No damage.
Ruggedness Output VSWR	10:1			ratio	No damage, conditions: max operating voltage, max input power
Stability Output VSWR	4:1			ratio	
Harmonics					
Second Band 2			-36	dBm	P_{OUT}=13dBm in 1MHz RBW @ 6Mbps
Second Band 3			-48	dBm	P_{OUT}=16dBm in 1MHz RBW @ 6Mbps
Second Band 4			-48	dBm	P_{OUT}=18dBm in 1MHz RBW @ 6Mbps
Third All Bands			-48	dBm	Rated power in 1MHz RBW @ 6Mbps
Turn-On/Off Time			1.0	µS	Output stable to within 90% of final gain, Note 1

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Receive					
Compliance					IEEE802.11a IEEE802.11j FCC CFR 15.247, 0.205, 0.209
Frequency	2.4		2.5	GHz	
Switch Leakage		2	6	μA	SW=High
Output Impedance 50Ω		-10	-9	dB	
Low Band LNA Enable Current		60	100	uA	
Enable Voltage	2.8	3	3.2	V	TLL, 200mV less than V_{CC}
High Gain Mode					SWRX=1, LNA2EN=1, SWTX=0
RX Gain	10	12	14	dB	
RX Gain Variation	-1.5		+1.5	dB	Over frequency range, full temperature range, and voltage
Noise Figure		3	3.2	dB	Across frequency
Input P1dB**	-4	-1		dBm	
Input IIP3		12			2-tone, P_{IN}=-20dBm, Δf=1MHz
Current Consumption		12	20	mA	
Low Gain Mode 1					SWRX=1, LNA2EN=1, SWTX=1
RX Gain	-2	0	+2		
Noise Figure		16		dB	Across frequency
Input P1dB		8		dBm	
IIP3		21		dBm	2-tone, P_{IN}=-13dBm, Δf=1MHz
Current Consumption		16	20	mA	
Low Gain Mode 2					SWRX=0, LNA2EN=1, SWTX=1
RX Gain	-19	-17	-15	dB	
Noise Figure		33			
Input P1dB		25		dBm	
IIP3		38		dBm	2-tone, P_{IN}=-15dBm, Δf=1MHz
Current Consumption		16	20	mA	
Low Gain Mode 3					SWRX=1, LNA2EN=0, SWTX=1
RX Gain	-43	-41	-39	dB	
Noise Figure		41		dB	
IIP3		TBD			
Current Consumption		0		mA	

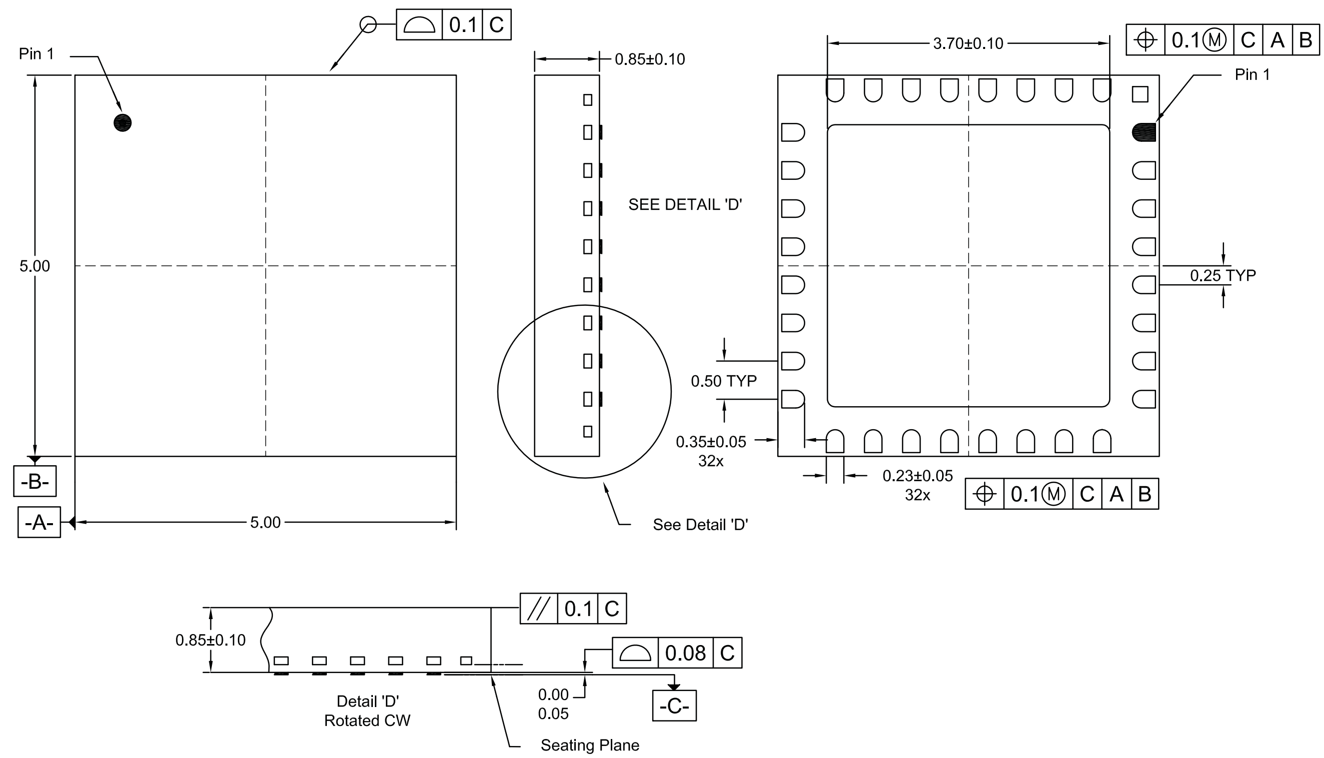
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
5.0GHz Receive					
Compliance					IEEE802.11a IEEE802.11j FCC CFR 15.247, 0.205, 0.209
Frequency	4.9		5.9	GHz	
Switch Leakage		2	6	μA	SW2=High
Output Impedance 50Ω		2.0:1		Ratio	
Passband Ripple		±1		dB	
High Gain Mode					SWRX=1, LNA5EN=1, SWTX=0
RX Gain	9	11	13	dB	P_{IN} to P_{IN}
RX Gain Variation	-1.5		+1.5	dB	Over frequency range, full temperature range, and voltage
Noise Figure		2.7	3.0	dB	25°C
Input P1dB	-5	-2		dBm	
IIP3		12			2-tone, P_{IN}=-20dBm, Δf=1MHz
Current Consumption		15	20	mA	
Low Gain Mode 1					SWRX=0, LNA5EN=1, SWTX=0
RX Gain	1	3	5	dB	
Noise Figure		11		dB	
Input P1dB		7		dBm	
IIP3		18.5		dBm	2-tone, P_{IN}=-15dBm, Δf=1MHz
Current Consumption		17	20	mA	
Low Gain Mode 2					SWRX=1, LNA5EN=0, SWTX=0
RX Gain	-33	-31	-29	dB	
Noise Figure		31		dB	
Input P1dB		16		dBm	
IIP3		21		dBm	2-tone, P_{IN}=-5dBm, Δf=1MHz
Current Consumption		0		mA	
Other Requirements					
Antenna Port Impedance					
Input		50		Ω	Receive
Output		50		Ω	Transmit
ESD Protection on Antenna Port	6			kV	No change in performance
ESD Protection on All Other Pins					
Human Body Model	500			V	No change in performance
Machine Model	500			V	No change in performance
Isolation					
Low Band RX - Off Antenna	17	20		dB	Low band transmit mode
High Band RX - Off Antenna	20	25		dB	High band transmit mode, LNA off
Total Module Leakage, V_{CC}, SW1, and SW2		5	15	uA	V_{CC}=SW1=SW2=3.6V PAEN2 and 5=LNAEN2 and 5=0.2V

Pin	Function	Description
1	SWTX	Switch control port. See truth table for details.
2	GND	Ground connection.
3	ANT	RF TX output for the 802.11b/g/a paths. It is matched to 50Ω and the DC block is provided internally.
4	GND	Ground connection.
5	SWRX	Switch control port. See truth table for details.
6	GND	Ground connection.
7	N/C	Pin 7 and Pin 8 have to be connected together on the PCB, but should not be connected to anything else on the board, see schematic for details.
8	N/C	Pin 7 and Pin 8 have to be connected together on the PCB, but should not be connected to anything else on the board.
9	PDET2	Power detector voltage for the 802.11b/g PA. P_{DET} voltage varies with output power. May need external decoupling capacitor for module stability. May need resistive voltage divider to bring output voltage to desired level.
10	N/C	No connection.
11	VCC	Main supply voltage for the third stage of the b/g power amplifier. This pin requires an external bypass capacitor.
12	VCC	Both pins 12 and 13 are the main supply voltage for the first and second stages of the b/g power amplifier. It is recommended that both pins 12 and 13 be connected on the PCB right at the footprints of these pins. Both pins require one bypass capacitor. See schematic for more details.
13	VCC	See pin 12 for details.
14	GND	Ground connection.
15	GND	Ground connection.
16	TX2_IN	RF input for the 802.11b/g PA. Input is matched to 50Ω and DC block is provided internally.
17	GND	Ground connection.
18	RX2	Receive port for 802.11b/g band.
19	PAEN2	Bias voltage for the 802.11b/g PA. Internally decoupled port with approximately 100pF.
20	LNAEN2	Bias voltage for the 802.11b/g LNA.
21	LNAEN5	Bias voltage for the 802.11a LNA.
22	PAEN5	Bias voltage for the 802.11a PA. Internally decoupled port with approximately 100pF.
23	RX5	Receive port for 802.11a band.
24	GND	Ground connection.
25	TX5_IN	TX RF input for the 802.11a PA. Input is matched to 50Ω and DC block is provided internally.
26	GND	Ground connection.
27	VCC	Main voltage supply for the first and second stages for the 11a power amplifier. This pin requires a bypass capacitor externally.
28	VCC	This pin requires a 1μF to ground. This pin is internally connected to VCC and should not be connected to VCC externally.
29	VCC	Main voltage supply to the third stage of the 11a power amplifier. This pin requires a bypass capacitor externally.
30	N/C	No Connect.
31	PDET5	Power detector voltage for the 802.11a PA. P_{DET} voltage varies with output power. May need external decoupling capacitor for module stability. May need resistive voltage divider to bring output voltage to desired level.
32	VCC	Main voltage supply.
Pkg GND	GND	Ground connection. The back side of the package should be connected to ground plane through as short a connection as possible, e.g., PCB vias under the device are recommended.

Switch Truth Table

PAEN2	LNA_EN2	PAEN5	LNAEN5	SWTX	SWRX	State
L	L	L	L	L	L	Low Power State
L	L	L	H	L	H	HB RX
L	H	L	L	L	H	LB RX
L	L	H	L	H	L	HB TX
H	L	L	L	H	L	LB TX

Package Drawing



PCB Design Requirements

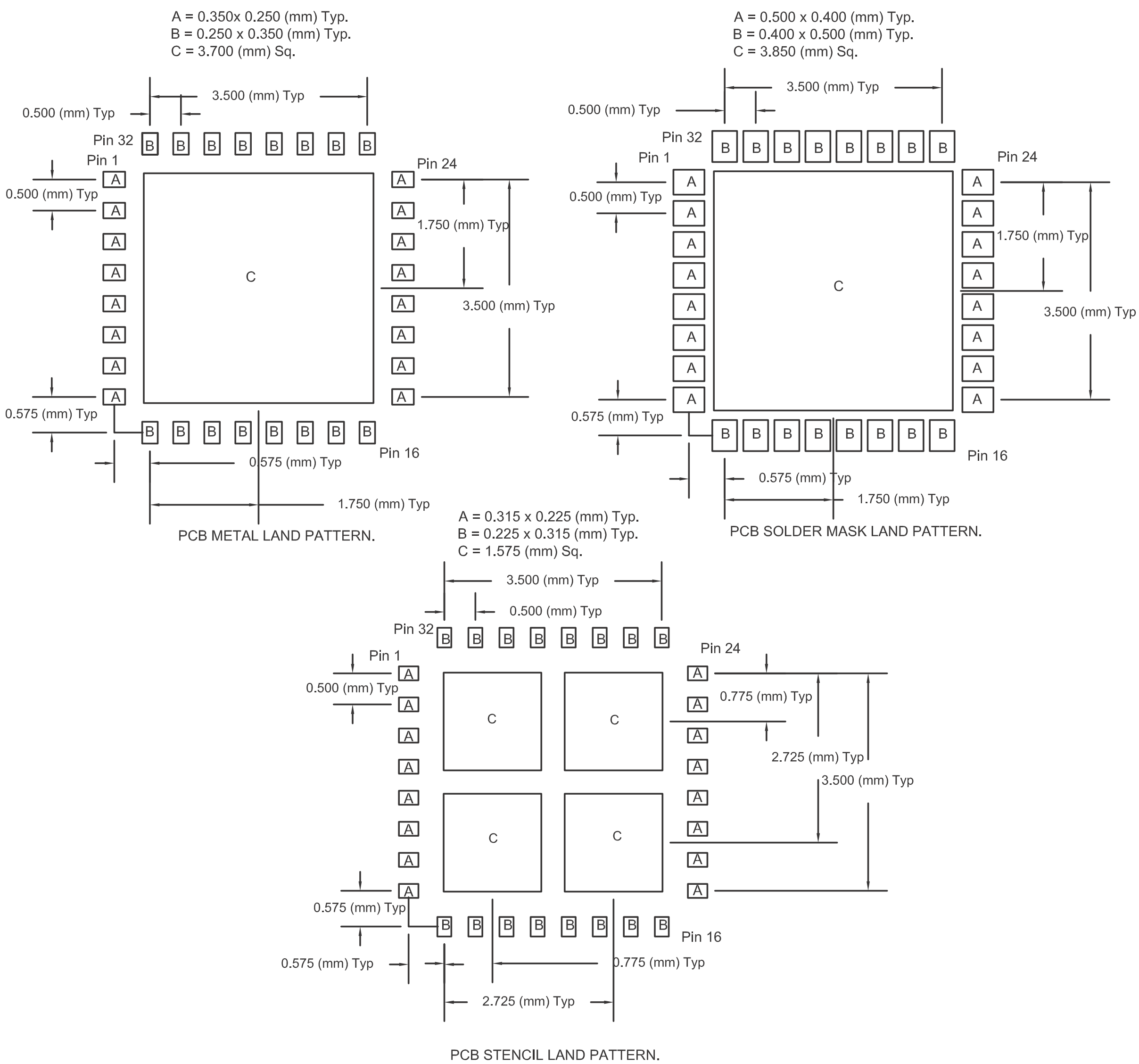
PCB Surface Finish

The PCB surface finish used for RFMD's qualification process is electroless nickel, immersion gold. Typical thickness is 3µinch to 8µinch gold over 180µinch nickel.

PCB Land Pattern Recommendation

PCB land patterns for RFMD components are based on IPC-7351 standards and RFMD empirical data. The pad pattern shown has been developed and tested for optimized assembly at RFMD. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

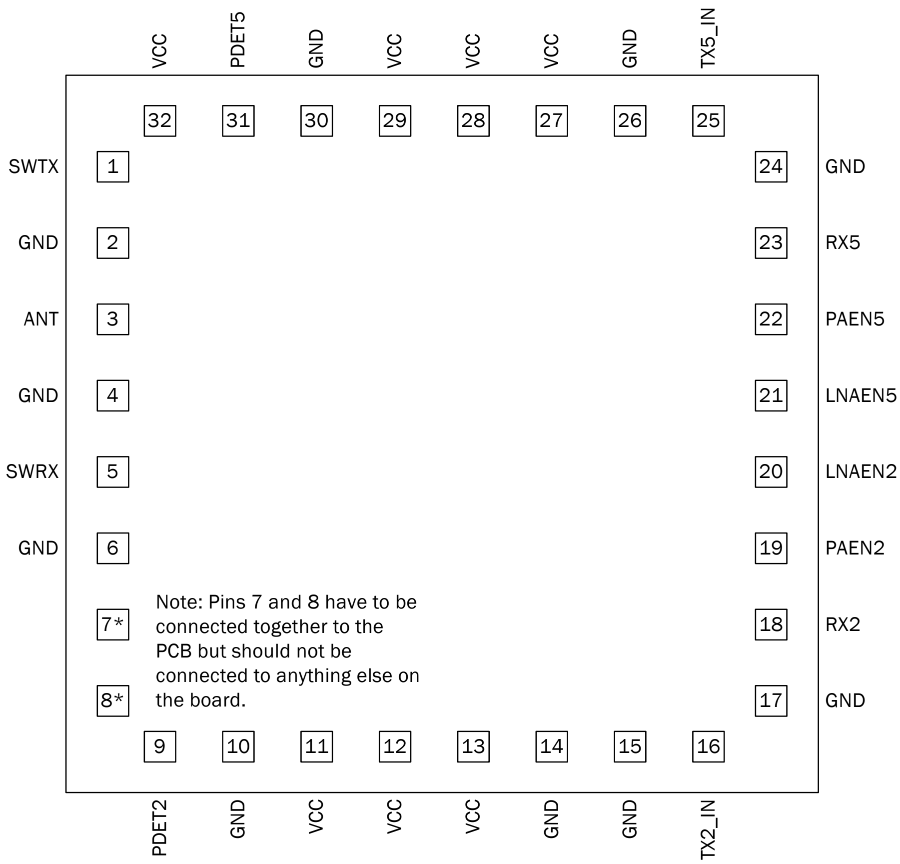
PCB Metal Land and Solder Mask Pattern



Thermal vias for center slug "C" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application. Example of the number and size of vias can be found on the RFMD evaluation board layout.

Pin Out

(Top View)



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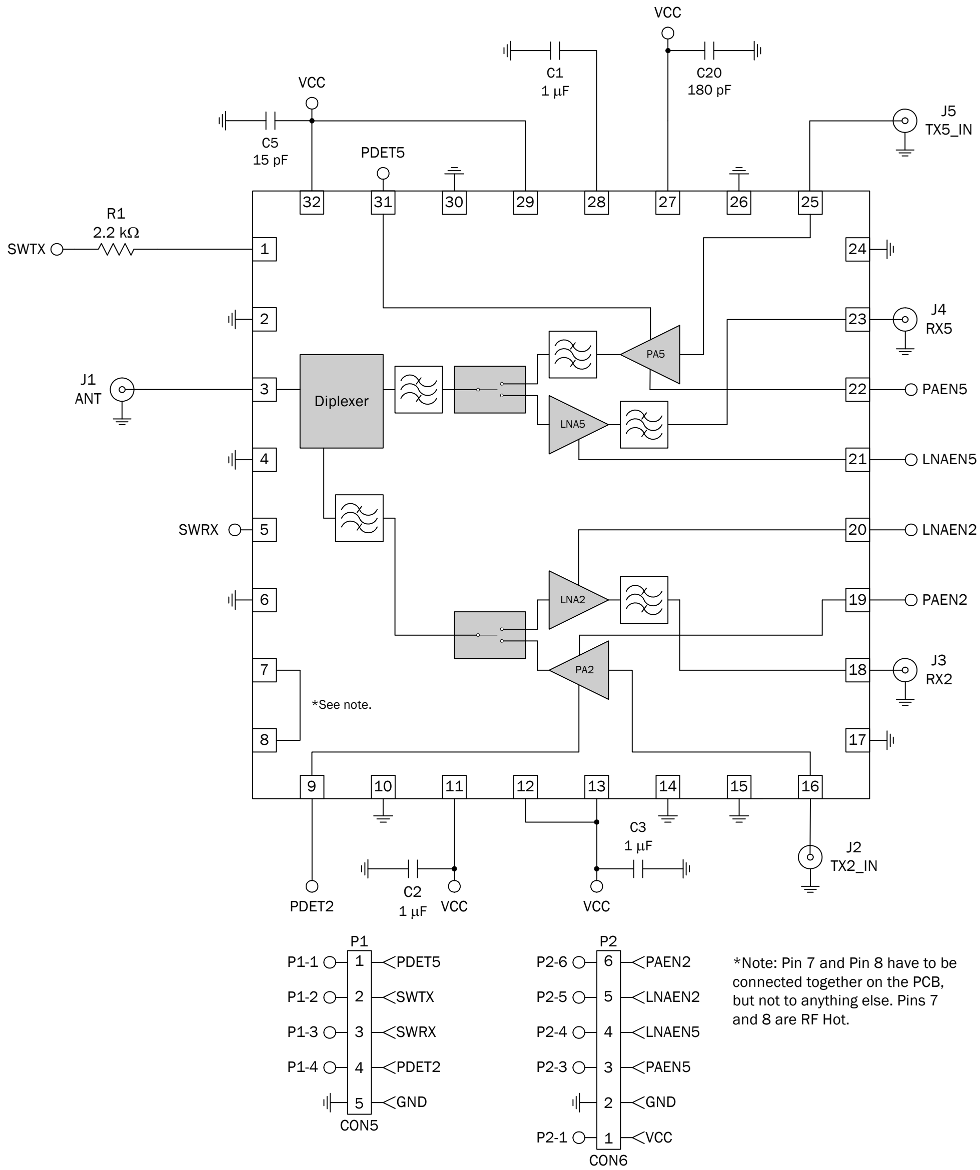
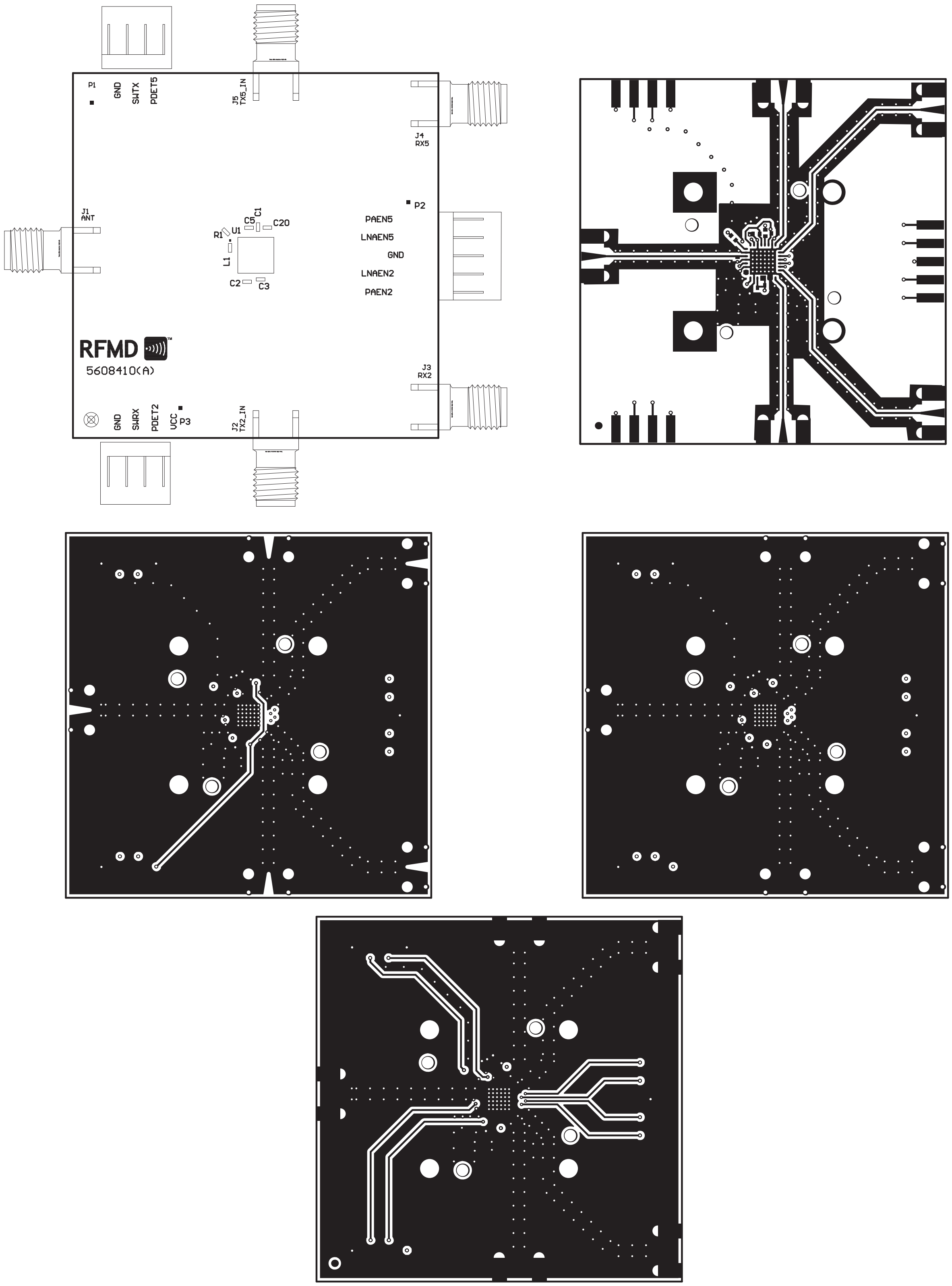
Evaluation Board Schematic



*Note: Pin 7 and Pin 8 have to be connected together on the PCB, but not to anything else. Pins 7 and 8 are RF Hot.

Evaluation Board Layout



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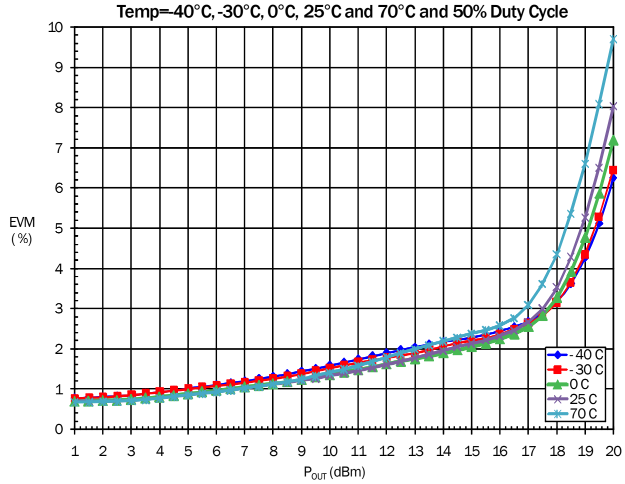
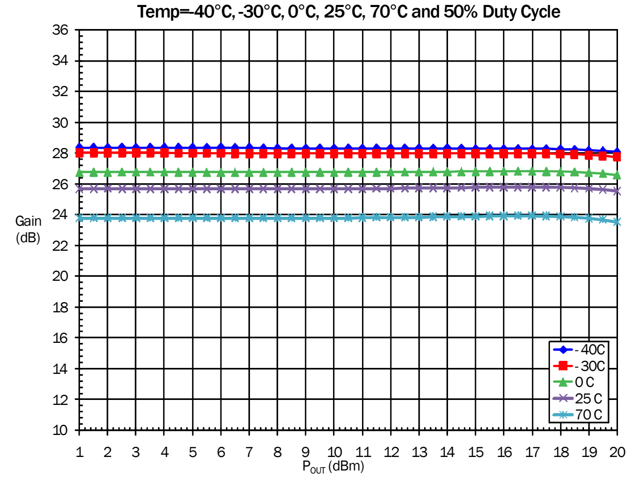
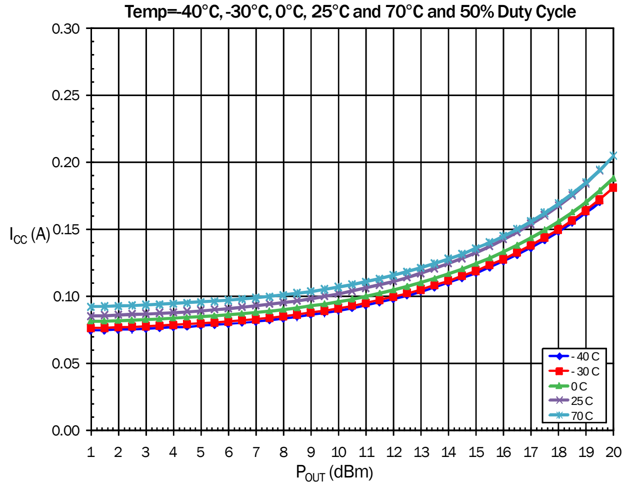
Low Band EVM versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=2.45, Temp=-40°C, -30°C, 0°C, 25°C and 70°C and 50% Duty Cycle



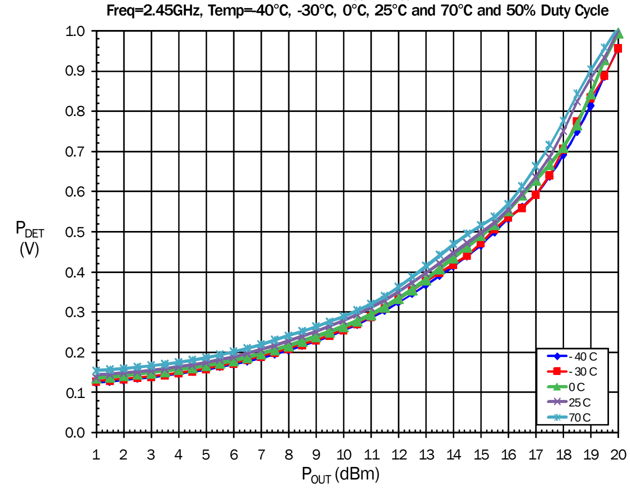
Low Band Gain versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=2.45, Temp=-40°C, -30°C, 0°C, 25°C, 70°C and 50% Duty Cycle



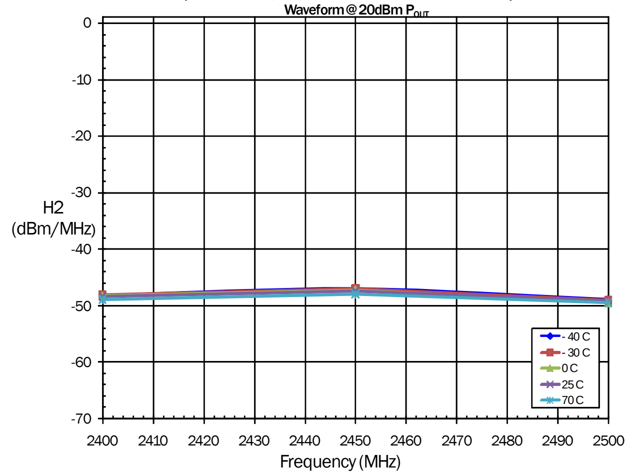
Low Band ICC versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=2.45, Temp=-40°C, -30°C, 0°C, 25°C and 70°C and 50% Duty Cycle



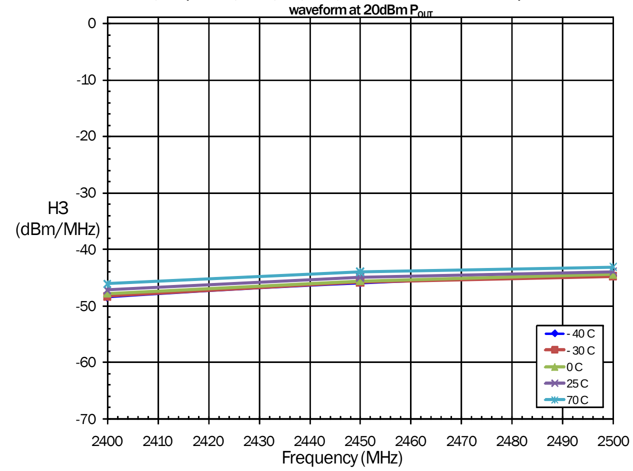
Low Band Pdetect versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=2.45GHz, Temp=-40°C, -30°C, 0°C, 25°C and 70°C and 50% Duty Cycle



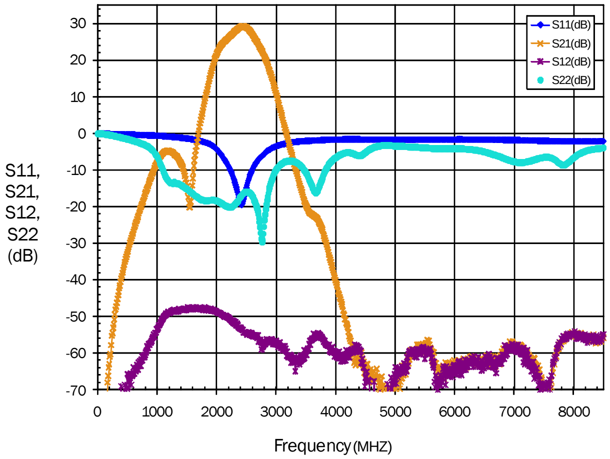
Low Band 2nd Harmonic versus Freq at V_{CC}=3.3V, PAENG=3.0V, Freq=2.4, 2.45, and 2.5GHz, Temp=-40°C, -30°C, 0°C, 25°C and 70°C Measured with 1Mbps IEEE802.11b Waveform @ 20dBm P_{OUT}



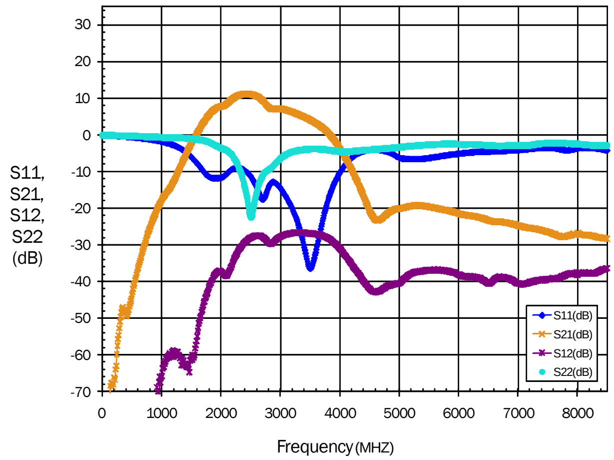
Low Band 3rd Harmonic versus Frequency at V_{CC}=3.3V, PAENG=3.0V, Freq=2.4, 2.45, and 2.5GHz, Temp=-40°C, -30°C, 0°C, 25°C, and 70°C. Measured with 1Mbps IEEE802.11b waveform at 20dBm P_{OUT}



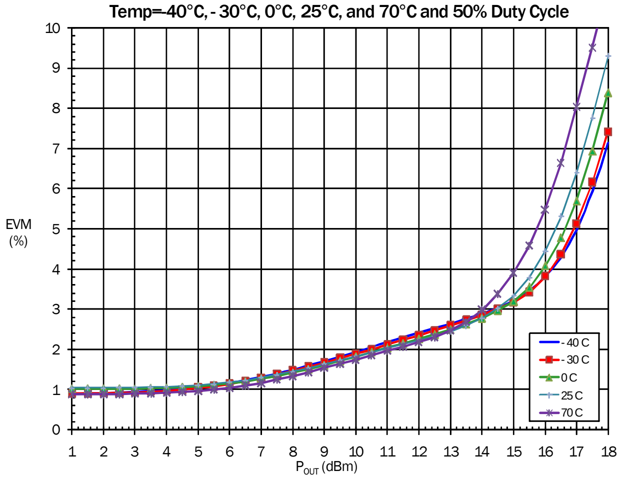
Low Band Typical TX Small Signal Plots at V_{CC}=3.3V, PAEN2=3.0V, SWTX=High, SWRX=Low, Freq=10MHz to 8500MHz, Temp=25°C



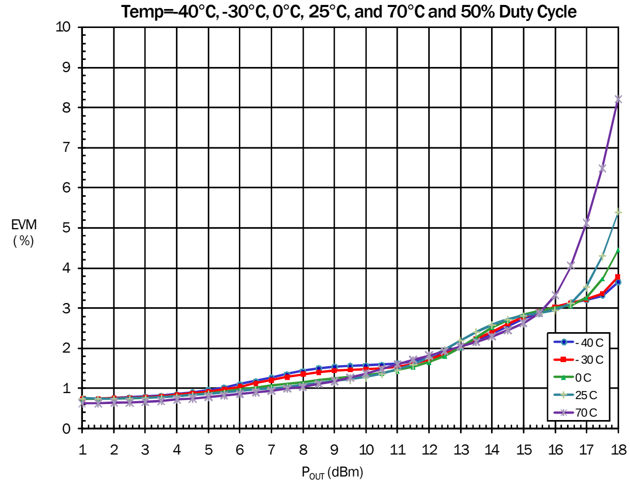
Low Band Typical RX Small Signal Plots at V_{CC}= 3.3V, LNAEN2=3.3V, SWTX=Low, SWRX=High, PAEN2=0V, Freq=10MHz to 8500MHz, Temp=25°C.



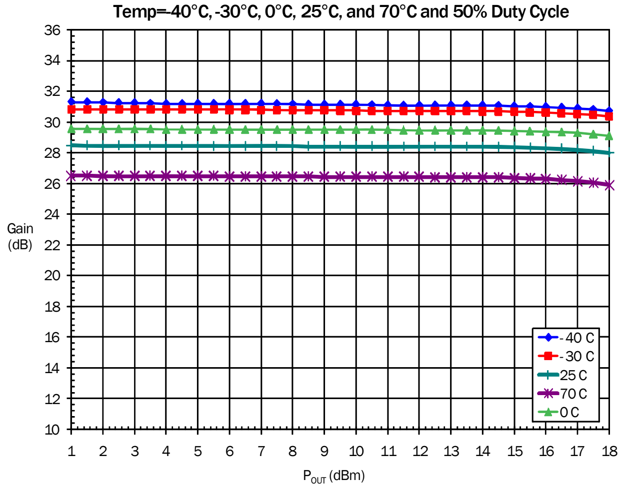
High Band EVM versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=5.1GHz Temp=-40°C, - 30°C, 0°C, 25°C, and 70°C and 50% Duty Cycle



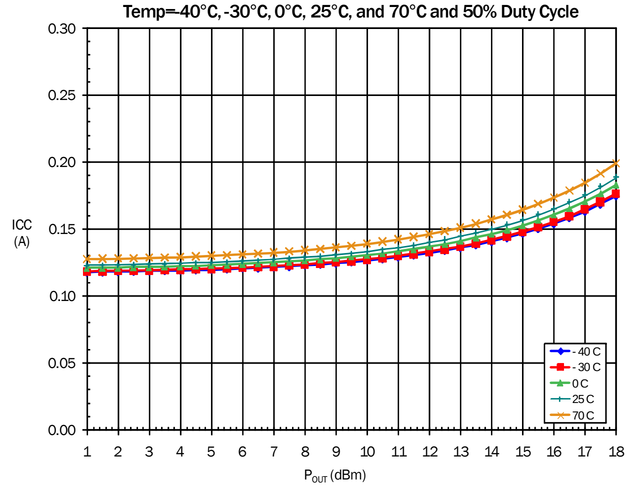
High Band EVM versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=5.85GHz Temp=-40°C, -30°C, 0°C, 25°C, and 70°C and 50% Duty Cycle



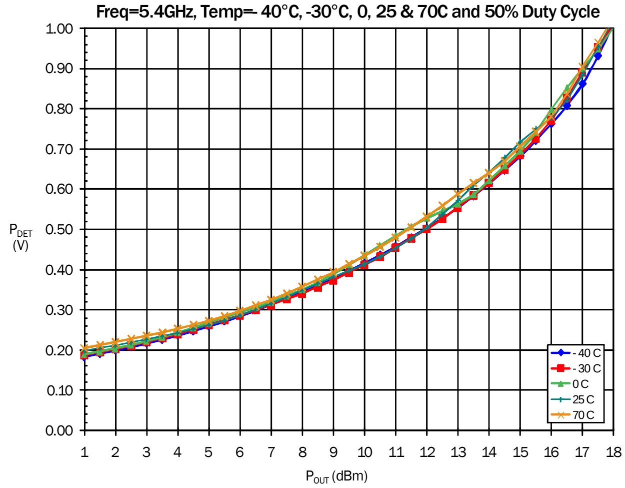
High Band Gain versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=5.4GHz, Temp=-40°C, -30°C, 0°C, 25°C, and 70°C and 50% Duty Cycle



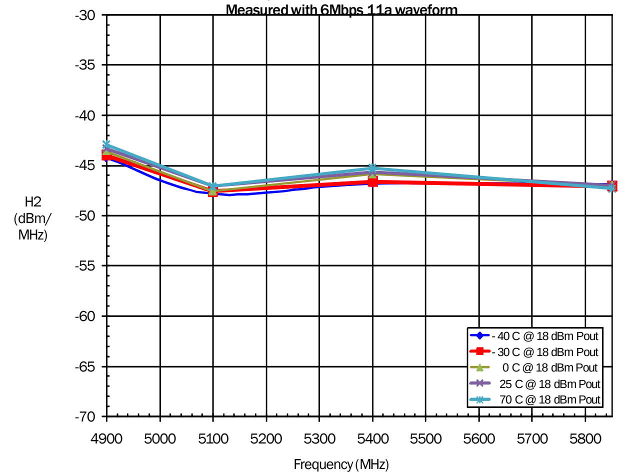
High Band ICC versus P_{OUT} at V_{CC}= 3.3V, PAENG=3.0V, Freq=5.4GHz, Temp=-40°C, -30°C, 0°C, 25°C, and 70°C and 50% Duty Cycle



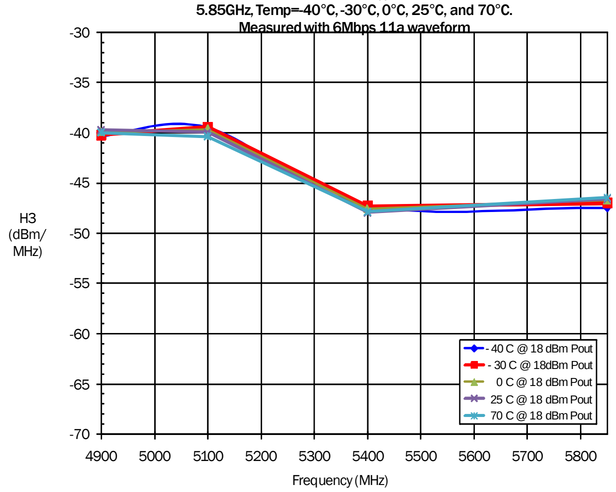
High Band P_{DETECT} versus P_{OUT} at V_{CC}=3.3V, PAENG=3.0V, Freq=5.4GHz, Temp=- 40°C, -30°C, 0, 25 & 70C and 50% Duty Cycle



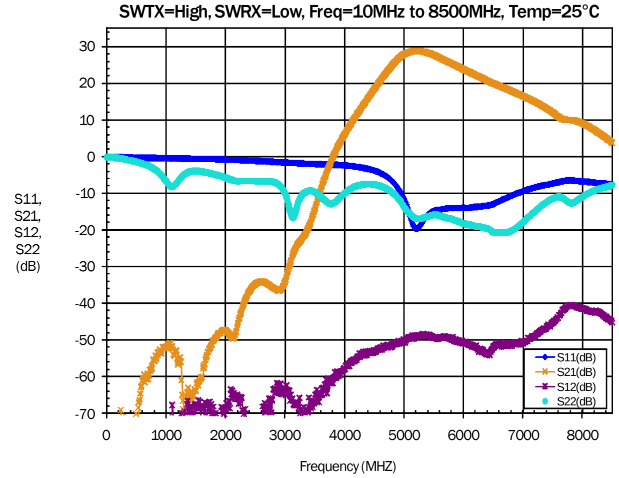
High Band 2nd Harmonic versus Freq at V_{CC}=3.3V, PAENG=3.0V, Freq=4.9 to 5.85GHz, Temp=-40°C, -30°C, 0°C, 25°C and 70°CC. Measured with 6Mbps 11a waveform



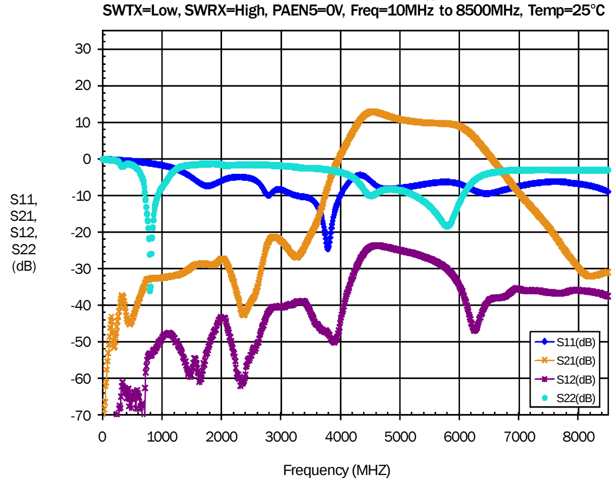
High Band 3rd Harmonic versus Freq at V_{CC}=3.3V, PAENG=3.0V, Freq=4.9 to 5.85GHz, Temp=-40°C, -30°C, 0°C, 25°C, and 70°C. Measured with 6Mbps 11a waveform



High Band Typical TX Small Signal Plots at V_{CC}=3.3V, PAEN5=3.0V, SWTX=High, SWRX=Low, Freq=10MHz to 8500MHz, Temp=25°C



High Band Typical RX Small signal Plots at V_{CC}=3.3V, LNAEN5=3.3V, SWTX=Low, SWRX=High, PAEN5=0V, Freq=10MHz to 8500MHz, Temp=25°C



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